NSN 5961-01-083-5610

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-083-5610 **Inclosure Material:** Glass **Overall Length:** 0.350 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.145 inches **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 200.0 reverse voltage, peak and 1.1 on voltage, forward voltage drop, dc **Current Rating Per Characteristic:** 1.20 amperes forward current, average absolute and 3.00 amperes forward current, average peak **Capacitance Rating In Picofarads:** 320.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 84347-181-655 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No